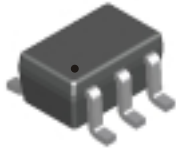


RoHS Compliant Product

SOT-363



*** Features**

Power dissipation

$$P_{CM} : 0.3 \text{ W (Tamp.} = 25^{\circ}\text{C)}$$

Collector current

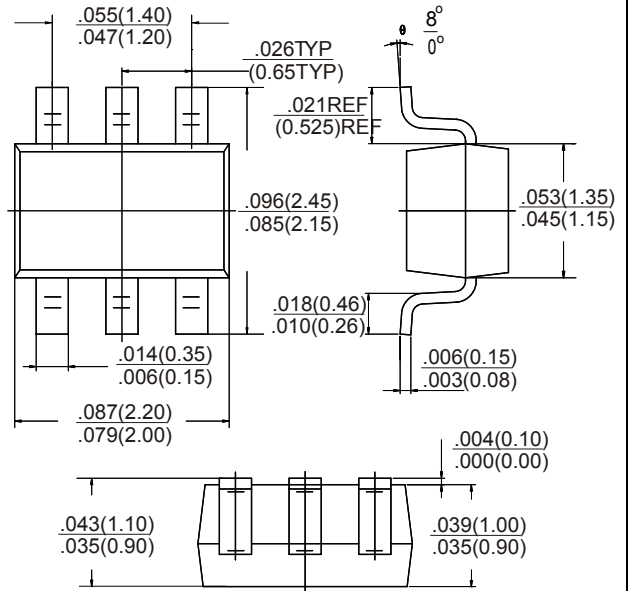
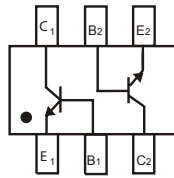
$$I_{CM} : 0.2 \text{ A}$$

Collector-base voltage

$$V_{(BR)CBO} : 50 \text{ V}$$

Operating & Storage junction Temperature

$$T_j, T_{stg} : -55^{\circ}\text{C} \sim +150^{\circ}\text{C}$$



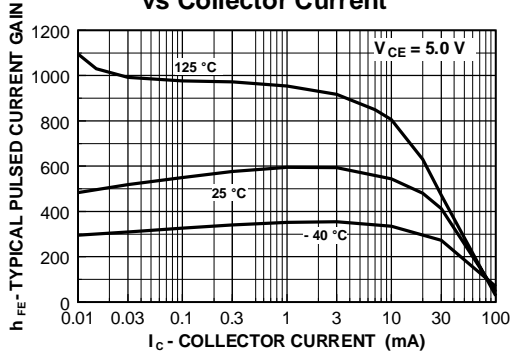
Dimensions in inches and (millimeters)

Electrical Characteristics(Tamb=25°C unless otherwise specified)

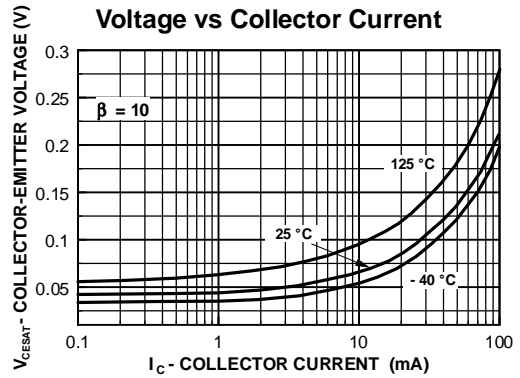
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6			V
Collector cut-off current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$			15	nA
DC current gain	$h_{FE(1)}$	$V_{CE}=5\text{V}, I_C=2\text{mA}$	110		630	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.25	V
	$V_{CE(sat)(2)}$	$I_C=100\text{mA}, I_B=5\text{mA}$			0.65	V
Base-emitter voltage	V_{BE}	$V_{CE}=5\text{V}, I_C=2\text{mA}$			0.7	V
	$V_{BE(2)}$	$V_{CE}=5\text{V}, I_C=10\text{mA}$			0.77	V
Transition frequency	f_T	$V_{CE}=5\text{V}, I_C=20\text{mA}, f=100\text{MHz}$		200		MHz
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$		2		pF

Typical Characteristics

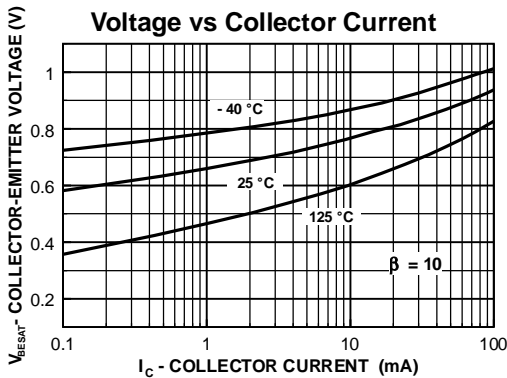
Typical Pulsed Current Gain vs Collector Current



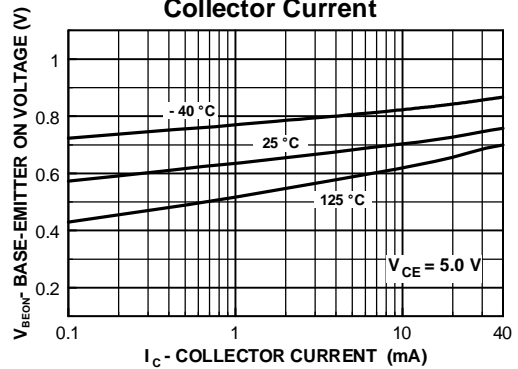
Collector-Emitter Saturation Voltage vs Collector Current



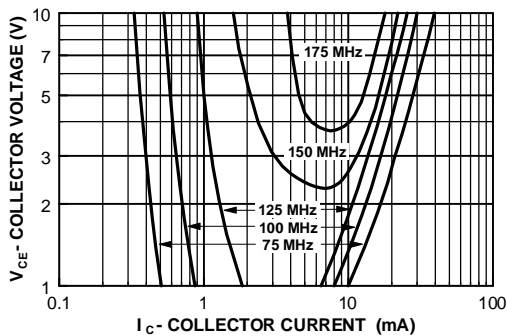
Base-Emitter Saturation Voltage vs Collector Current



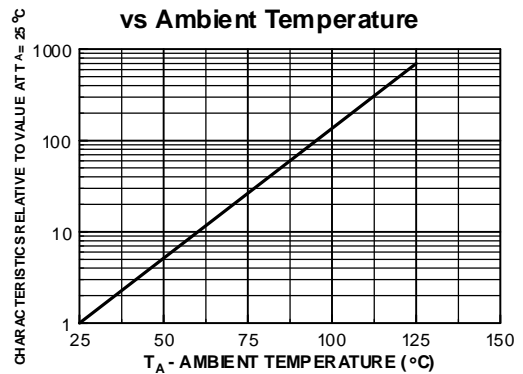
Base-Emitter ON Voltage vs Collector Current



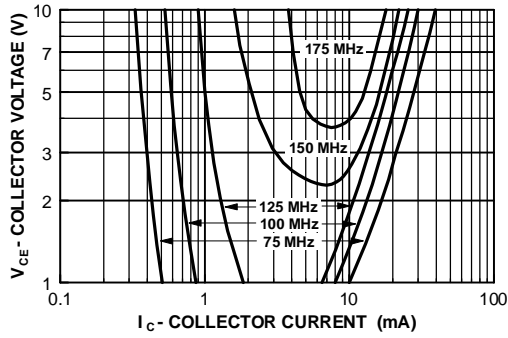
Contours of Constant Gain Bandwidth Product (f_T)



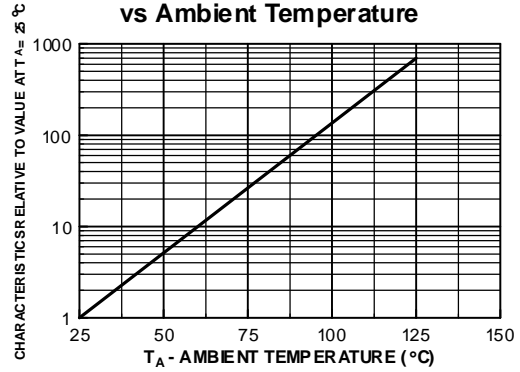
Normalized Collector-Cutoff Current vs Ambient Temperature



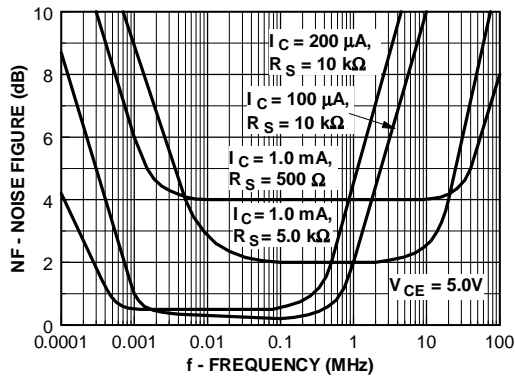
Contours of Constant Gain Bandwidth Product (f_T)



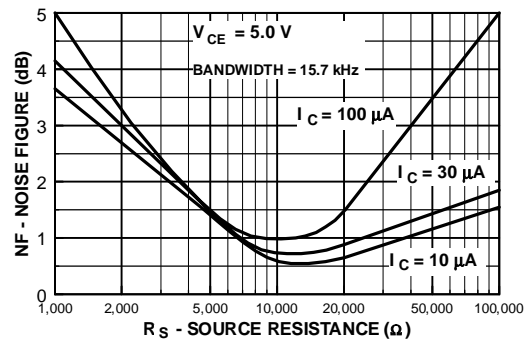
Normalized Collector-Cutoff Current vs Ambient Temperature



Noise Figure vs Frequency



Wideband Noise Frequency vs Source Resistance



Power Dissipation vs Ambient Temperature

